

U74AHC2G125

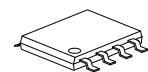
CMOS IC

DUAL BUFFER/LINE DRIVER; 3-STATE

■ DESCRIPTION

The **U74AHC2G125** is a high speed, Si-gate CMOS device.

The **U74AHC2G125** provides a dual non-inverting buffer/line drivers with 3-state output. The 3-state output is controlled by the output enable input ($n\bar{O}E$). A HIGH at $n\bar{O}E$ causes the output to assume a high-impedance OFF-state.



TSSOP-8

■ FEATURES

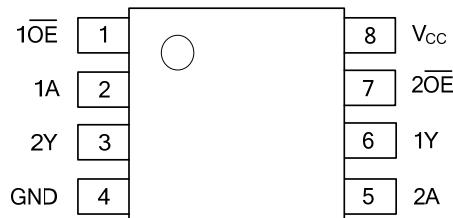
- * Symmetrical output impedance
- * High noise immunity
- * Low power dissipation
- * Balanced propagation delays
- * Multiple package options
- * Specified from -40 °C to +125 °C

■ ORDERING INFORMATION

| Ordering Number | | Package | Packing |
|--------------------|--------------------|---------|-----------|
| Lead Free | Halogen Free | | |
| U74AHC2G125L-P08-T | U74AHC2G125G-P08-T | TSSOP-8 | Tube |
| U74AHC2G125L-P08-R | U74AHC2G125G-P08-R | TSSOP-8 | Tape Reel |

| | |
|--|---|
| U74AHC2G125L-P08-T (1)Packing Type (2)Package Type (3)Lead Free | (1) T: Tube, R: Tape Reel (2) P08: TSSOP-8 (3) L: Lead Free, G:Halogen Free |
|--|---|

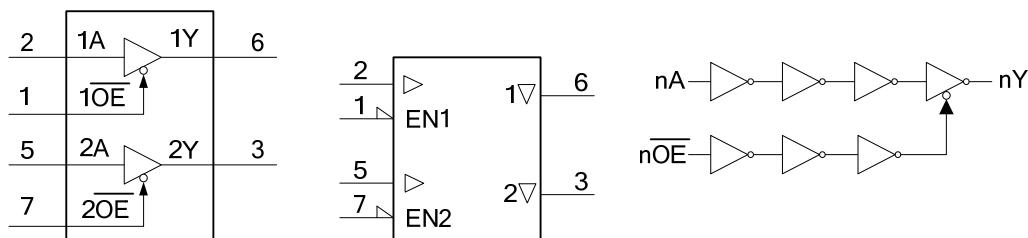
■ PIN CONFIGURATION



■ PIN CONFIGURATION

| PIN No | SYMBOL | DESCRIPTION |
|--------|-------------------------------------|----------------------------------|
| 1, 7 | $\overline{1OE}$, $\overline{2OE}$ | Output enable input (active LOW) |
| 2, 5 | 1A, 2A | Data input |
| 4 | GND | Ground (0V) |
| 6, 3 | 1Y, 2Y | Data output |
| 8 | V_{CC} | Supply voltage |

■ FUNCTIONAL DIAGRAM



LOGIC SYMBOL

IEC LOGIC SYMBOL

LOGIC DIAGRAM (one driver)

■ FUNCTION TABLE

| Control | Input | Output |
|------------------|-------|--------|
| $n\overline{OE}$ | nA | nY |
| L | L | L |
| L | H | H |
| H | X | Z |

H=HIGH voltage level; L=LOW voltage level; X=don't care; Z=high-impedance OFF-state

■ ABSOLUTE MAXIMUM RATING

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------------|-----------|--|------|-----|----------|------|
| Supply Voltage | V_{CC} | | -0.5 | | +7.0 | V |
| Input Voltage | V_I | | -0.5 | | +7.0 | V |
| Input Clamping Current | I_{IK} | $V_I < -0.5V$ | -20 | | | mA |
| Output Clamping Current | I_{OK} | $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$ | | | ± 20 | mA |
| Output Current | I_O | $V_O = -0.5V \sim (V_{CC} + 0.5V)$ | | | ± 25 | mA |
| Supply Current | I_{CC} | | | | 75 | mA |
| Ground Current | I_{GND} | | -75 | | | mA |
| Power Dissipation | P_D | | | | 300 | mW |
| Storage Temperature | T_{STG} | | -65 | | +150 | °C |

Note: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

■ RECOMMENDED OPERATING CONDITIONS

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------------------------|---------------------|------------------------|-----|-----|----------|------|
| Supply Voltage | V_{CC} | | 2 | 5 | 5.5 | V |
| Input Voltage | V_I | | 0 | | 5.5 | V |
| Output Voltage | V_O | | 0 | | V_{CC} | V |
| Input Transition Rise and Fall Rate | $\Delta t/\Delta V$ | $V_{CC}=3.3V \pm 0.3V$ | | | 100 | ns/V |
| | | $V_{CC}=5V \pm 0.5V$ | | | 20 | |
| Ambient Temperature | T_A | | -40 | +25 | +125 | °C |

Note: Voltages are referenced to GND (ground=0V).

■ ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ C$, unless otherwise specified)

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------------|----------|--|------|-----|-----------|---------|
| High-level Input Voltage | V_{IH} | $V_{CC}=2V$ | 1.5 | | | V |
| | | $V_{CC}=3V$ | 2.1 | | | |
| | | $V_{CC}=5.5V$ | 3.85 | | | |
| Low-level Input Voltage | V_{IL} | $V_{CC}=2V$ | | | 0.5 | V |
| | | $V_{CC}=3V$ | | | 0.9 | |
| | | $V_{CC}=5.5V$ | | | 1.65 | |
| Output Voltage High-level | V_{OH} | $V_{CC}=2V, I_{OH}=-50\mu A$ | 1.9 | 2.0 | | V |
| | | $V_{CC}=3V, I_{OH}=-50\mu A$ | 2.9 | 3.0 | | |
| | | $V_{CC}=4.5V, I_{OH}=-50\mu A$ | 4.4 | 4.5 | | |
| | | $V_{CC}=3V, I_{OH}=-4mA$ | 2.58 | | | |
| | | $V_{CC}=4.5V, I_{OH}=-8mA$ | 3.94 | | | |
| Output Voltage Low-level | V_{OL} | $V_{CC}=2V, I_{OL}=50\mu A$ | | 0 | 0.1 | V |
| | | $V_{CC}=3V, I_{OL}=50\mu A$ | | 0 | 0.1 | |
| | | $V_{CC}=4.5V, I_{OL}=50\mu A$ | | 0 | 0.1 | |
| | | $V_{CC}=3V, I_{OL}=4mA$ | | | 0.36 | |
| | | $V_{CC}=4.5V, I_{OL}=8mA$ | | | 0.36 | |
| Input Leakage Current | I_I | $V_{CC}=0$ to $5.5V$, $V_I=5.5V$ or GND | | | ± 0.1 | μA |
| OFF-state output current | I_{OZ} | $V_{CC}=5.5V$, $V_I=V_{CC}$ or GND | | | 0.25 | μA |
| Quiescent Supply Current | I_{CC} | $V_{CC}=5.5V$, $V_I=V_{CC}$ or GND, $I_O=0$ | | | 1 | μA |

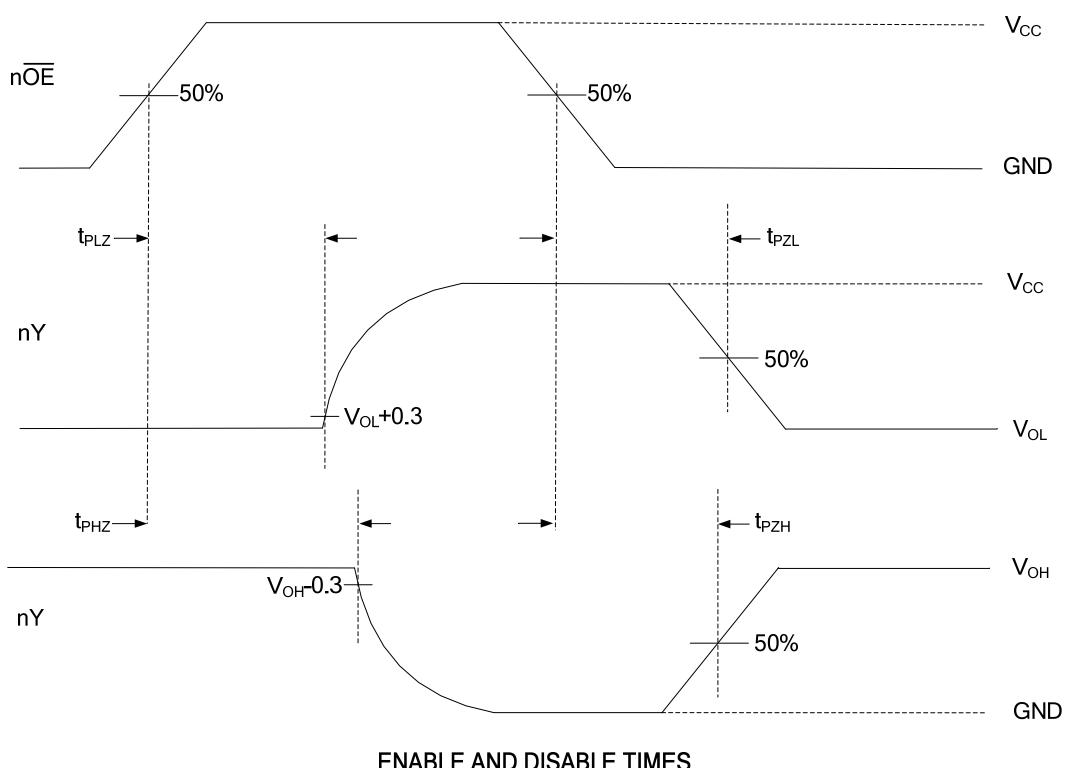
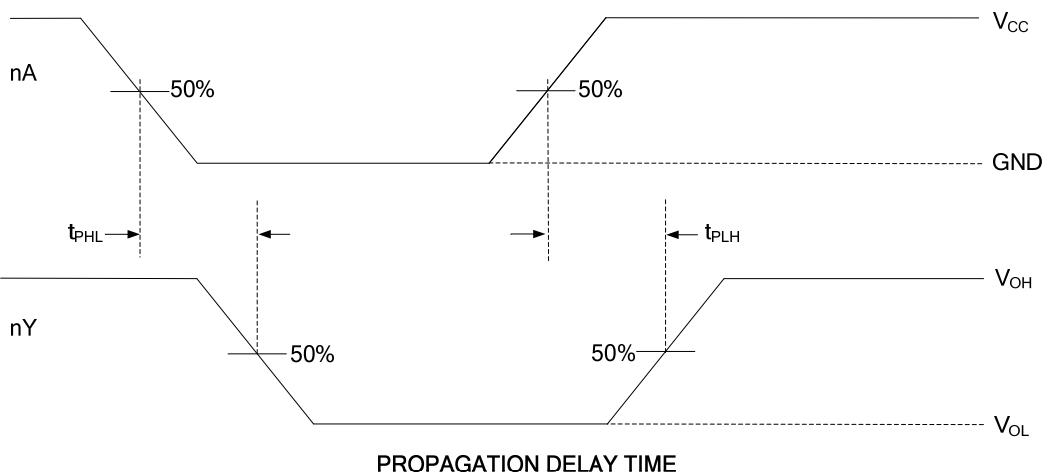
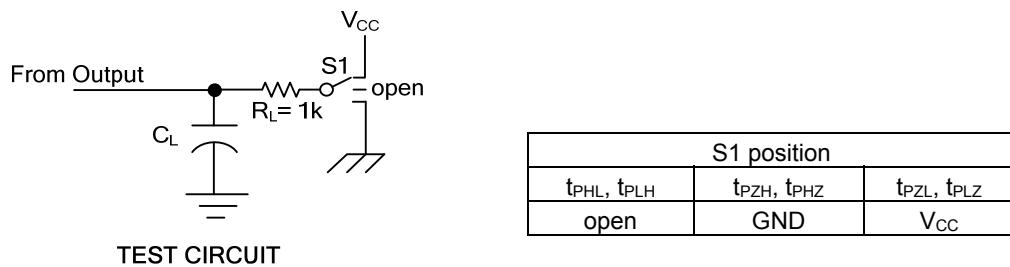
■ SWITCHING CHARACTERISTICS ($t_r = t_f \leq 3\text{ns}$, $T_A = 25^\circ\text{C}$, unless otherwise specified)

| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|--|---------------------|------------------------------|-------------------|-----|-----|------|------|
| Propagation delay from input (nA) to output (nY) | t_{PLH} / t_{PHL} | $V_{CC}=3\sim 3.6\text{V}$ | $C_L=15\text{pF}$ | | 4.7 | 8.0 | ns |
| | | | $C_L=50\text{pF}$ | | 6.6 | 11.5 | ns |
| | | $V_{CC}=4.5\sim 5.5\text{V}$ | $C_L=15\text{pF}$ | | 3.4 | 5.5 | ns |
| | | | $C_L=50\text{pF}$ | | 4.8 | 7.5 | ns |
| Enable time from $n\overline{OE}$ to nY | t_{PZL} / t_{PZH} | $V_{CC}=3\sim 3.6\text{V}$ | $C_L=15\text{pF}$ | | 5.0 | 8.0 | ns |
| | | | $C_L=50\text{pF}$ | | 6.9 | 11.5 | ns |
| | | $V_{CC}=4.5\sim 5.5\text{V}$ | $C_L=15\text{pF}$ | | 3.6 | 5.1 | ns |
| | | | $C_L=50\text{pF}$ | | 4.9 | 7.5 | ns |
| Disable time from $n\overline{OE}$ to nY | t_{PLZ} / t_{PHZ} | $V_{CC}=3\sim 3.6\text{V}$ | $C_L=15\text{pF}$ | | 6.0 | 9.7 | ns |
| | | | $C_L=50\text{pF}$ | | 8.3 | 13.2 | ns |
| | | $V_{CC}=4.5\sim 5.5\text{V}$ | $C_L=15\text{pF}$ | | 4.1 | 6.8 | ns |
| | | | $C_L=50\text{pF}$ | | 5.7 | 8.8 | ns |

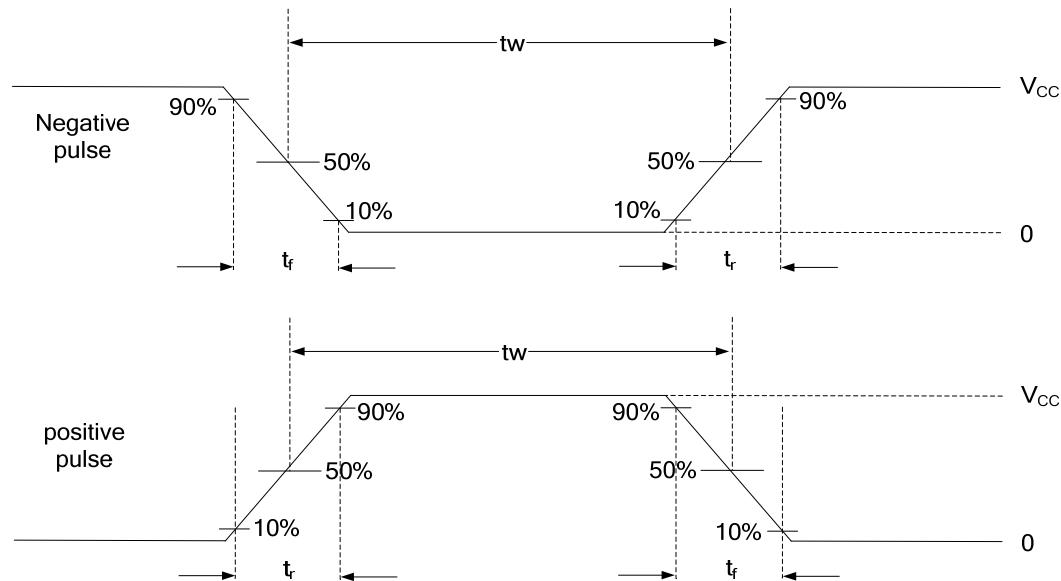
■ CAPACITIVE CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise specified)

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------------------|----------|--|-----|-----|-----|------|
| Input Capacitance | C_I | | | 1.5 | 10 | pF |
| Power Dissipation Capacitance | C_{PD} | per buffer; $C_L=50\text{pF}$; $f_i=1\text{MHz}$; $V_i=\text{GND}$ to V_{CC} | | 9 | | pF |

■ TEST CIRCUIT AND WAVEFORMS



■ TEST CIRCUIT AND WAVEFORMS (Cont.)



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.